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M185-2.5/LM285-2.5/LM385-2.5 Micropower Voltage Reference Diode

LM185-2.5/LM285-2.5/LM385-2.5

Micropower Voltage Reference Diode

General Description

The LM185-2.5/LM285-2.5/LM385-2.5 are micropower 2-terminal band-gap voltage regulator diodes. Operating over a 20 µA to 20 mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM-185-2.5 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

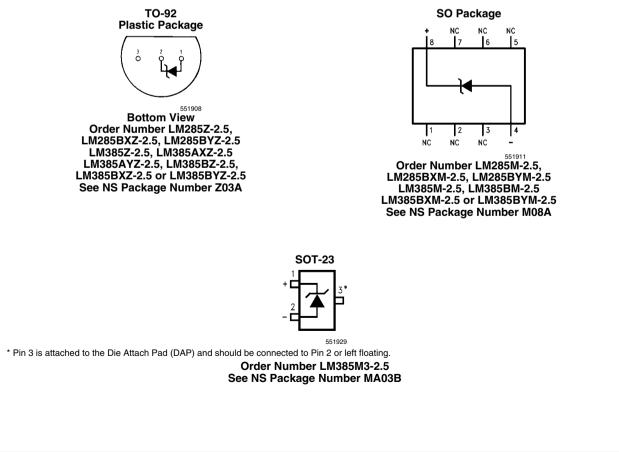
Careful design of the LM185-2.5 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-2.5 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the wide operating current allows it to replace older references with a tighter tolerance part. For applications requiring 1.2V see LM185-1.2.

The LM185-2.5 is rated for operation over a -55°C to 125°C temperature range while the LM285-2.5 is rated -40°C to 85° C and the LM385-2.5 0°C to 70°C. The LM185-2.5/LM285-2.5 are available in a hermetic TO-46 package and the LM285-2.5/LM385-2.5 are also available in a low-cost TO-92 molded package, as well as S.O. and SOT-23. The LM185-2.5 is also available in a hermetic leadless chip carrier package.

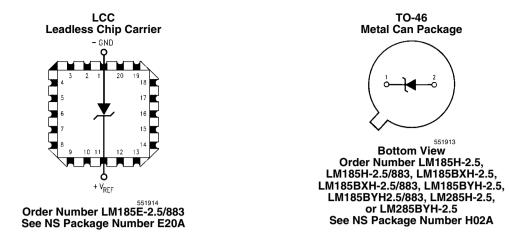
Features

- ±20 mV (±0.8%) max. initial tolerance (A grade)
- Operating current of 20 µA to 20 mA
- 0.6Ω dynamic impedance (A grade)
- Low temperature coefficient -
- Low voltage reference-2.5V
- 1.2V device and adjustable device also available-LM185-1.2 series and LM185 series, respectively





Connection Diagrams



LM185-2.5/LM285-2.5/LM385-2.5

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Reverse Current	30 mA
Forward Current	10 mA
Operating Temperature Range (Note 3)	
LM185-2.5	–55°C to + 125°C
LM285-2.5	-40°C to + 85°C
LM385-2.5	0°C to 70°C

Electrical Characteristics

(Note 4)

ESD Susceptibility (Note 9)	2kV
Storage Temperature	–55°C to + 150°C
Soldering Information	
TO-92 Package (10 sec.)	260°C
TO-46 Package (10 sec.)	300°C
SO and SOT Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Parameter	Conditions	Tur	LM385A-2.5 LM385AX-2.5 LM385AY-2.5		Units
	Conditions	Тур	Tested Limit (Note 5)	Design Limit (Note 6)	(Limits)
Reverse Breakdown	I _B = 100 μA	2.500	2.480		V(Min)
Voltage		2.500	2.520	2.470 2.530	V(Max) V(Min) V(Max)
Minimum Operating Current		12	18	20	μA (Max)
Reverse Breakdown Voltage Change with	$I_{MIN} \le I_R \le 1mA$		1	1.5	mV (Max)
Current	$1 \text{ mA} \leq I_{\text{R}} \leq 20 \text{ mA}$		10	20	mV (Max)
Reverse Dynamic Impedance	I _R = 100 μA, f = 20 Hz	0.2		0.6 1.5	Ω
Wideband Noise (rms)	I _R = 100 μA 10 Hz ≤ f ≤ 10 kHz	120			μV
Long Term Stability	$I_{R} = 100 \ \mu A,$ T = 1000 Hr, T _A = 25°C ±0.1°C	20			ppm
Average Temperature Coefficient (Note 7)	I _{MIN} ≤ I _R ≤ 20 mA X Suffix Y Suffix		30 50		ppm/°C (Max)
	All Others			150	

Electrical Characteristics									
Parameter	Conditions	Тур	LM185-2.5 LM185BX-2.5 LM185BY-2.5 LM285-2.5 LM285BX-2.5 LM285BY-2.5 Tested Design		LM385B-2.5 LM385BX-2.5 LM385BY-2.5 Tested Design		LM385-2.5		Units (Limit)
			Limit	Limit	Limit	Limit	Limit	Limit	
			(Notes 5, 8)	(Note 6)	(Note 5)	(Note 6)	(Note 5)	(Note 6)	
Reverse Breakdown	T _A = 25°C,	2.5	2.462		2.462		2.425		V(Min)
Voltage	20 µA ≤ I _R ≤ 20 mA		2.538		2.538		2.575		V(Max)
Minimum Operating		13	20	30	20	30	20	30	μA
Current	LM385M3-2.5						15	20	(Max)
Reverse Breakdown Voltage	20 µA ≤ I _R ≤ 1 mA		1	1.5	2.0	2.5	2.0	2.5	mV (Max)
Change with Current	1 mA ≤ I _R ≤ 20 mA		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	I _R = 100 μA, f = 20 Hz	1							Ω
Wideband Noise (rms)	Ι _R = 100 μΑ,	120							μV
	10 Hz ≤ f ≤ 10 kHz								
Long Term Stability	I _R = 100 μA, T = 1000 Hr, T _A = 25°C ±0.1°C	20							ppm
Average	I _R = 100 μA								
Temperature Coefficient (Note 7)	X Suffix Y Suffix All Others		30 50	150	30 50	150		150	ppm/°C ppm/°C ppm/°C (Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H-2.5 for military specifications.

Note 3: For elevated temperature operation, T_{JMAX} is:

LM185 150°C

LM285 125°C

LM385 100°C

Thermal Resistance	TO-92	TO-46	SO-8	SOT-23
θ_{ia} (Junction to Ambient)	180°C/W (0.4 Leads)	440°C/W	165°C/W	283°C/W
	170°C/W (0.125 Leads)			
θ_{jc} (Junction to Case)	N/A	80°C/W	N/A	N/A

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at $T_A = T_J = 25^{\circ}C$.

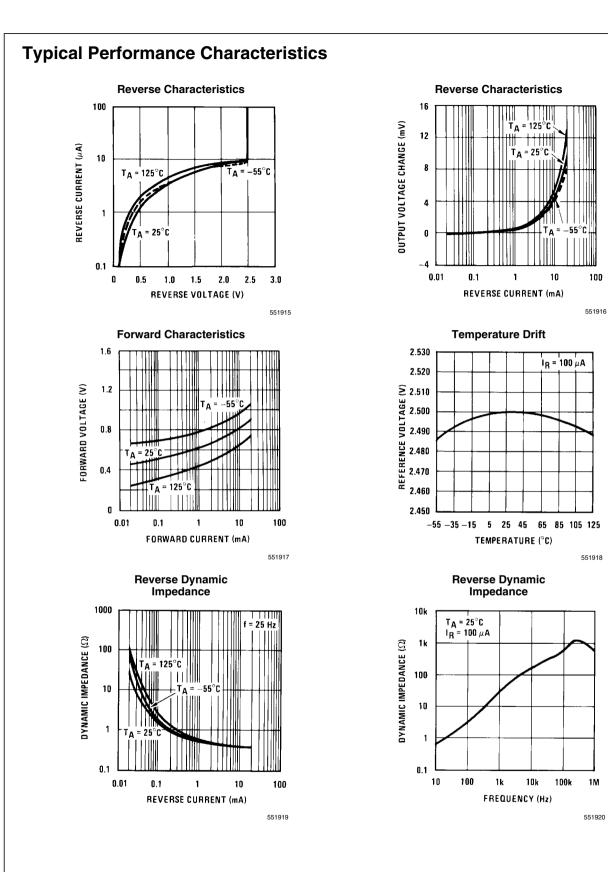
Note 5: Guaranteed and 100% production tested.

Note 6: Guaranteed, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.

Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN} , divided by T_{MAX} - T_{MIN} . The measured temperatures are -55°C, -40°C, 0°C, 25°C, 70°C, 85°C, 125°C.

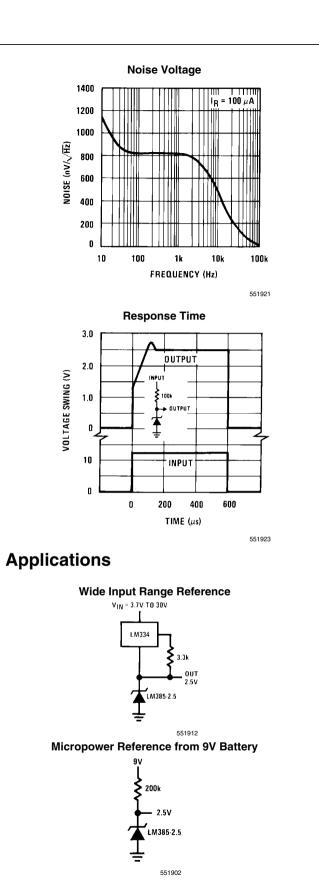
Note 8: A military RETS electrical specification available on request.

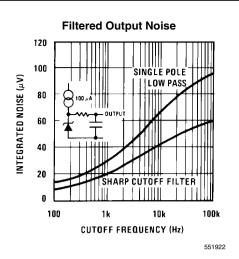
Note 9: The human body model is a 100 pF capacitor discharged through a 1.5 $k\Omega$ resistor into each pin.



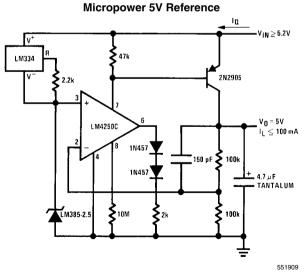
LM185-2.5/LM285-2.5/LM385-2.5



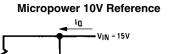


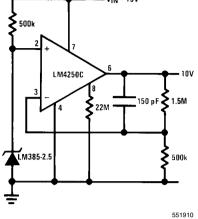


LM385-2.5 Applications



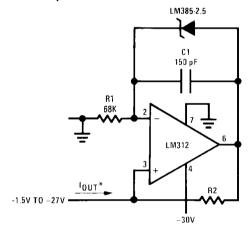
Note 10: I_Q ≃ 40 μA



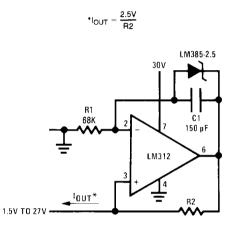


Note 11: $I_Q \simeq 30 \ \mu A$ standby current





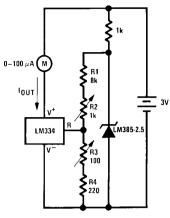
551924



551925

METER THERMOMETERS

0°C–100°C Thermomemter

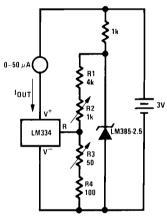


551926

Calibration

1. Short LM385-2.5, adjust R3 for I_{OUT} =temp at 1µA/°K Remove short, adjust R2 for correct reading in centigrade



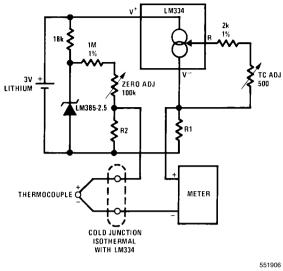


551927

Calibration

1. Short LM385-2.5, adjust R3 for $I_{OUT} = temp$ at 1.8 $\mu A/^{\circ} K$ Remove short, adjust R2 for correct reading in $^{\circ} F$

Micropower Thermocouple Cold Junction Compensator

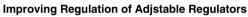


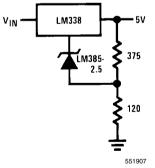
Adjustment Procedure

- 1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
- 2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

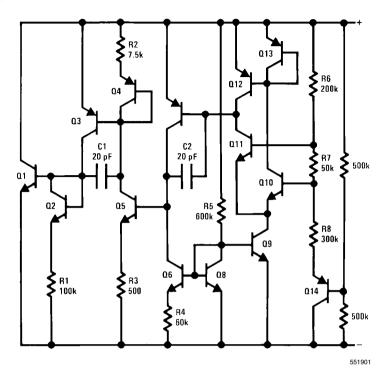
Thermocouple Type	Seebeck Co- efficient (_u V/°C)	R1 (Ω)	R2 (Ω)	Voltage Across R1 @25°C (mV)	Voltage Across R2 (mV)
J	52.3	523	1.24k	15.60	14.32
Т	42.8	432	1k	12.77	11.78
К	40.8	412	953Ω	12.17	11.17
S	6.4	63.4	150Ω	1.908	1.766

Typical supply current 50 µA

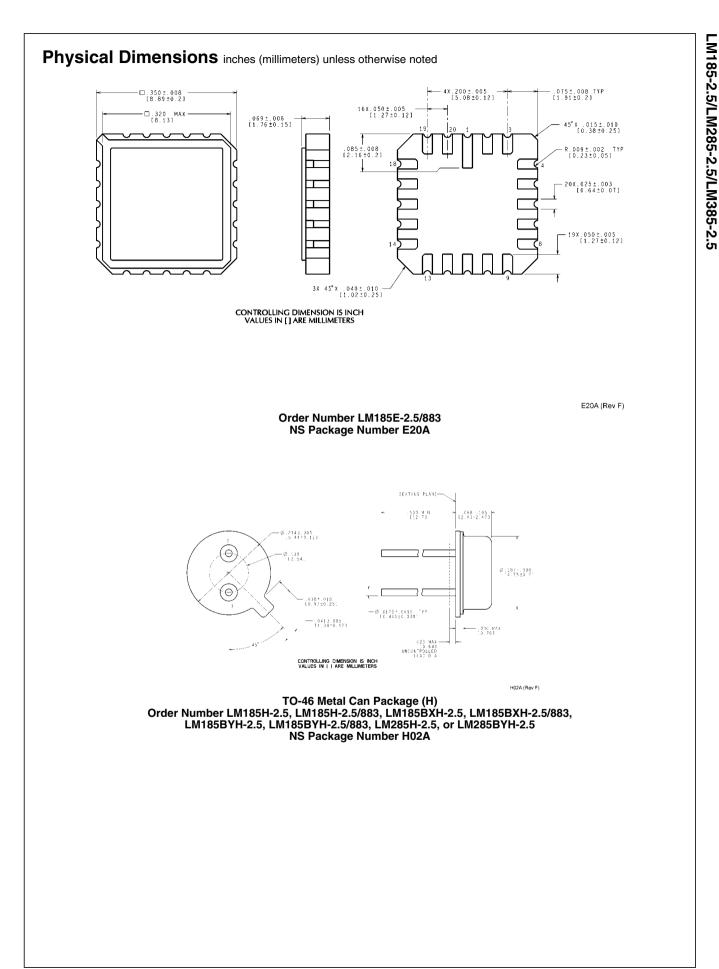




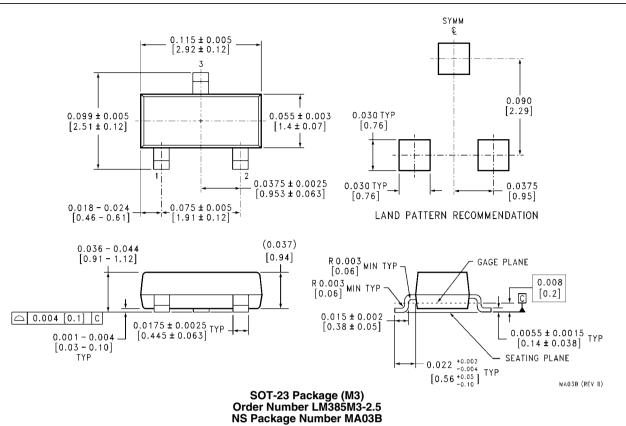
Schematic Diagram

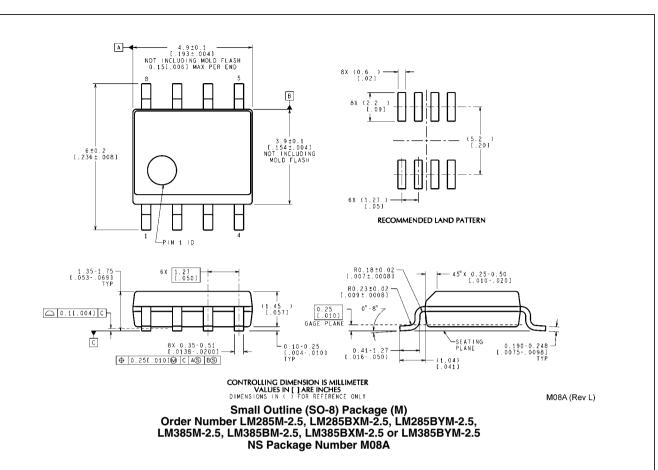


LM185-2.5/LM285-2.5/LM385-2.5

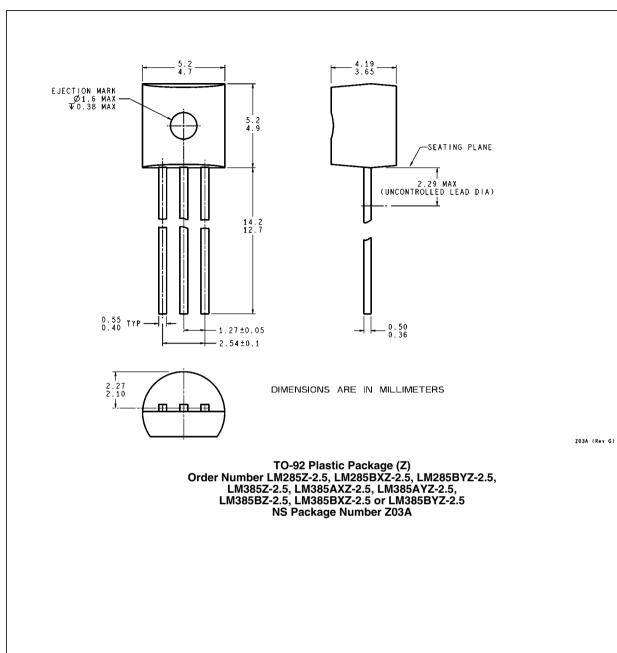








LM185-2.5/LM285-2.5/LM385-2.5



Notes

Notes

Products		Design Support		
Amplifiers	www.national.com/amplifiers	WEBENCH	www.national.com/webench	
Audio	www.national.com/audio	Analog University	www.national.com/AU	
Clock Conditioners	www.national.com/timing	App Notes	www.national.com/appnotes	
Data Converters	www.national.com/adc	Distributors	www.national.com/contacts	
Displays	www.national.com/displays	Green Compliance	www.national.com/quality/green	
Ethernet	www.national.com/ethernet	Packaging	www.national.com/packaging	
Interface	www.national.com/interface	Quality and Reliability	www.national.com/quality	
LVDS	www.national.com/lvds	Reference Designs	www.national.com/refdesigns	
Power Management	www.national.com/power	Feedback	www.national.com/feedback	
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